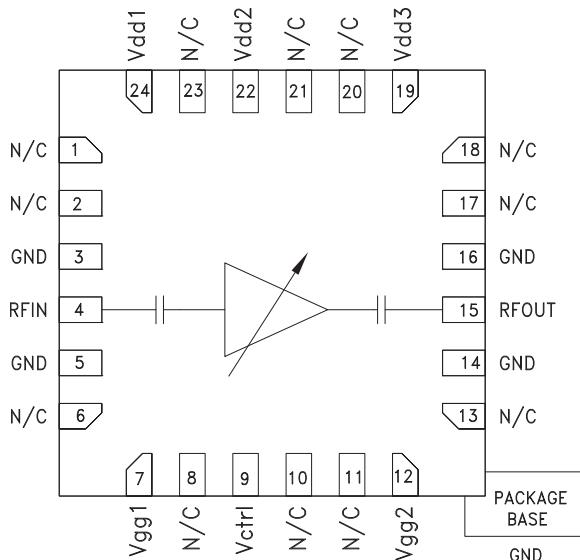



**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Typical Applications

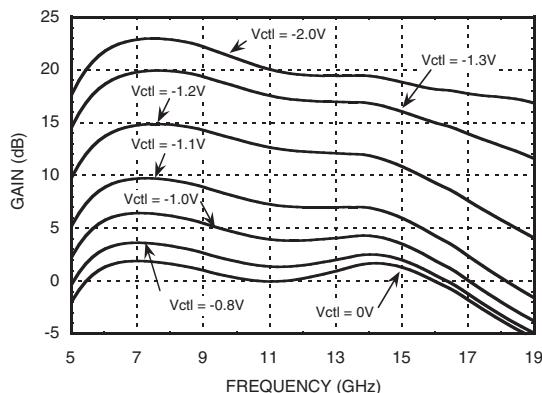
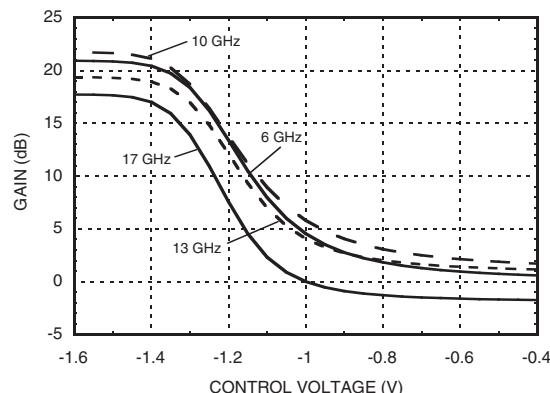
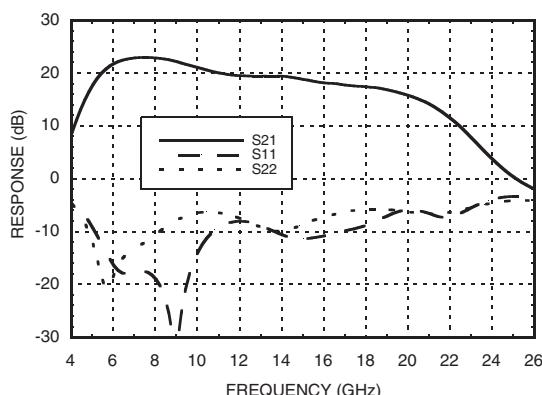
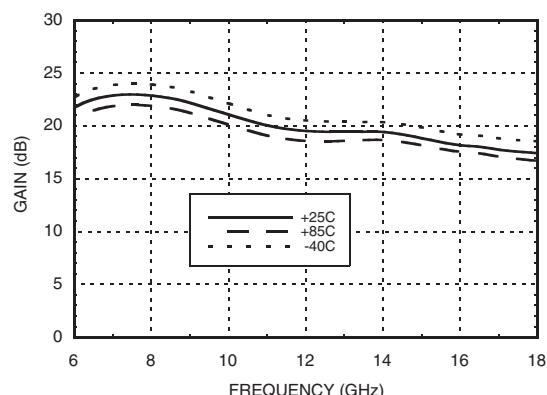
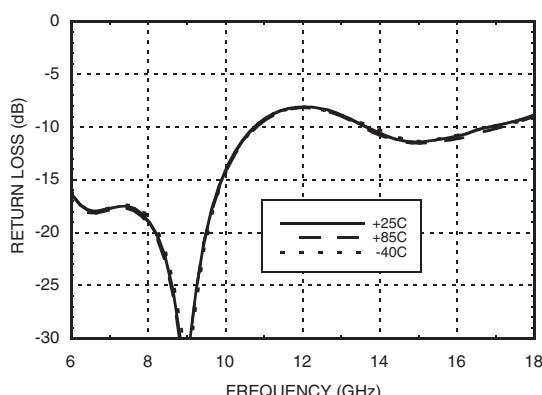
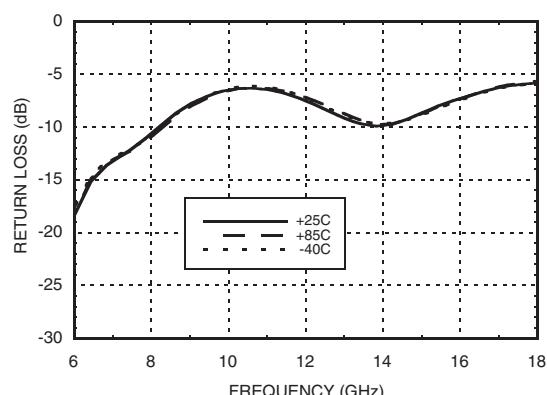
The HMC694LP4(E) is ideal for:

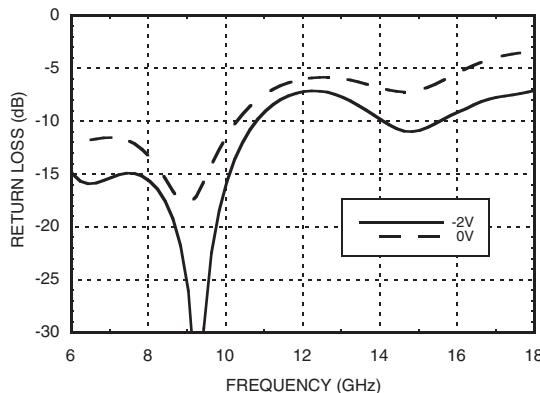
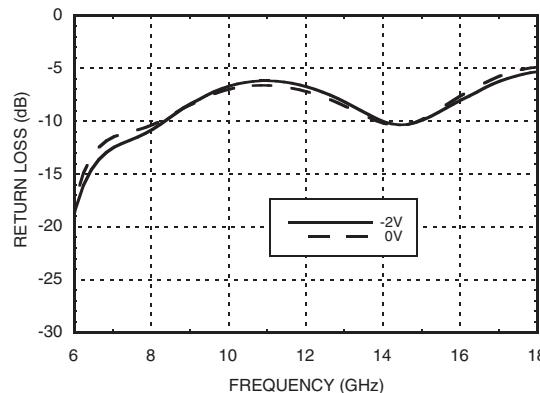
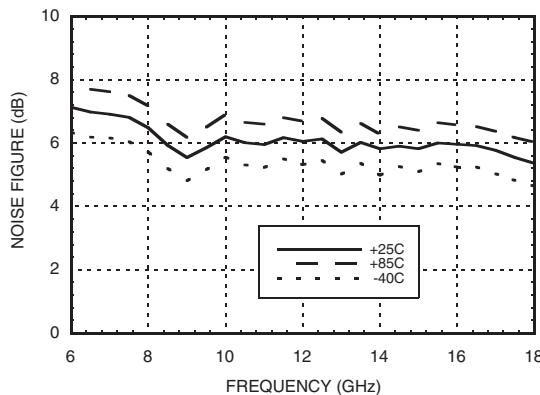
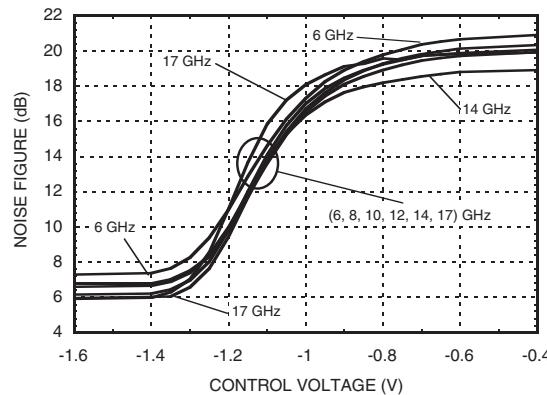
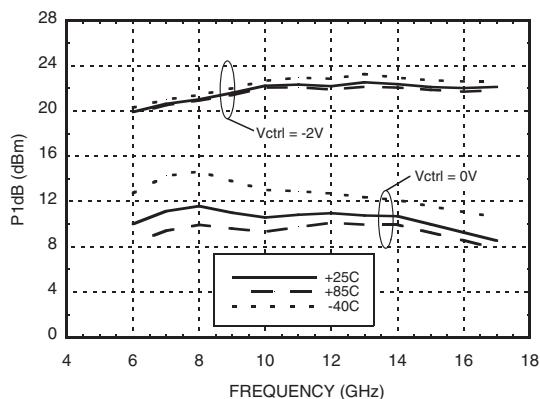
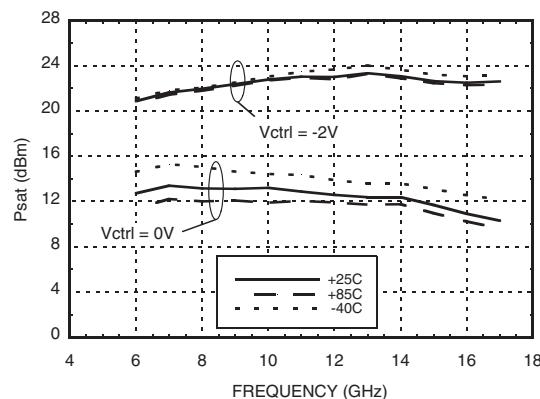
- Point-to-Point Radio
- Point-to-Multi-Point Radio
- EW & ECM
- X-Band Radar
- Test Equipment

Functional Diagram

Electrical Specifications, $T_A = +25^\circ\text{C}$, $Vdd1, 2, 3 = 5\text{V}$, $Vctrl = -2\text{V}$, $Idd = 170\text{ mA}^*$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	6 - 10			10 - 17			GHz
Gain	19	22		14	18		dB
Gain Flatness		± 1			± 1.5		dB
Gain Variation Over Temperature		0.015			0.015		dB/ $^\circ\text{C}$
Gain Control Range		23			20		dB
Noise Figure		6	7.5		6	6.5	dB
Input Return Loss		15			8		dB
Output Return Loss		10			8		dB
Output Power for 1 dB Compression (P1dB)	19	21		21	22		dBm
Saturated Output Power (Psat)		22			23		dBm
Output Third Order Intercept (IP3)		30			30		dBm
Total Supply Current (Idd)		175			175		mA

*Set Vctrl = -2V and then adjust Vgg1, 2 between -2V to 0V (typ. -0.8V) to achieve Idd = 170mA typical.

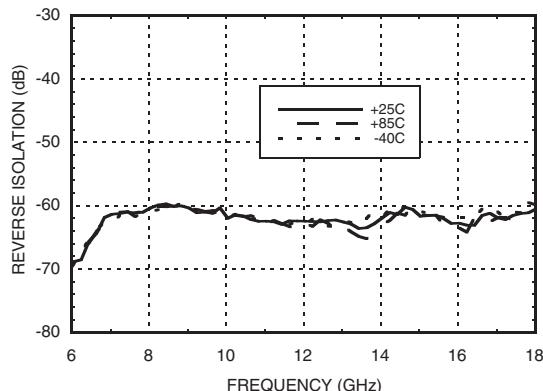
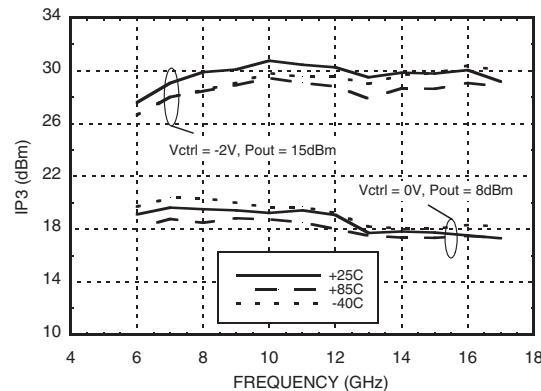
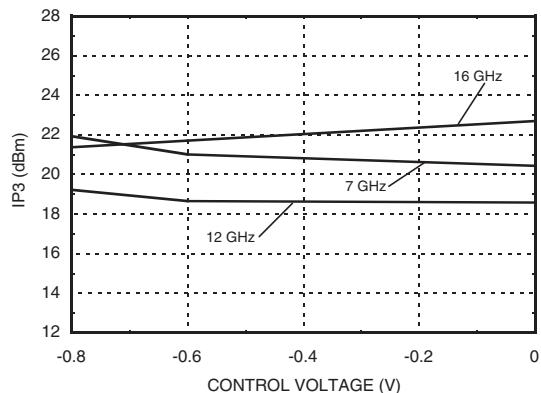
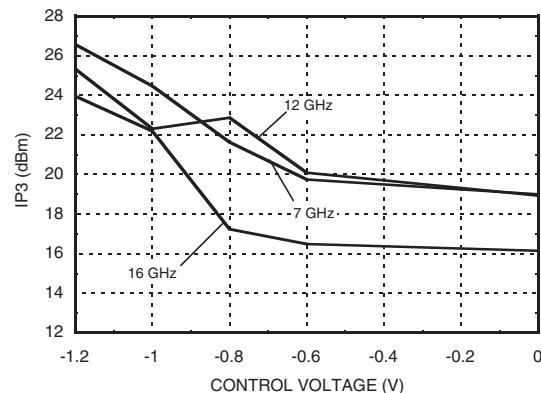
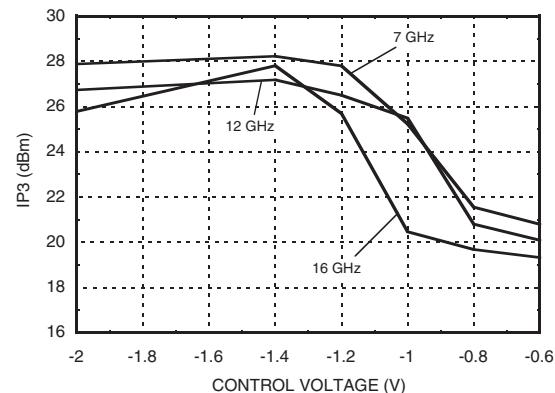

**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Control Voltage Range vs. Gain

Gain vs. Control Voltage

Broadband Gain & Return Loss

Gain vs. Temperature

Input Return Loss vs. Temperature

Output Return Loss vs. Temperature



**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Return Loss @ Voltage Extreme

Output Return Loss @ Voltage Extreme

Noise Figure vs. Temperature

Noise Figure vs. CTRL

P1dB vs. Temperature

Psat vs. Temperature


[1] Tested with broadband bias tee on RF ports and $C_1 = 10,000\text{pF}$
 [2] C_1, C_6 and $C_8 = 100\text{pF}$, $L_1 = 24\text{nH}$

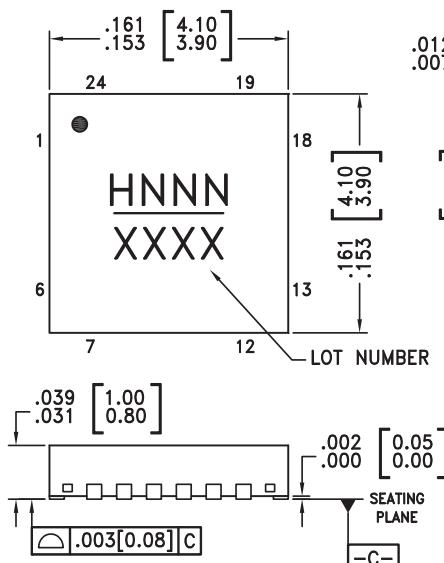
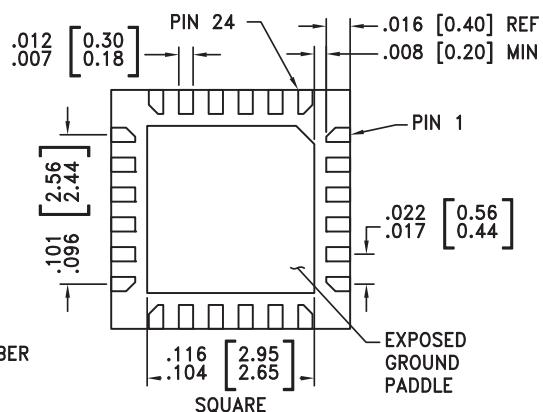
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**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Reverse Isolation vs. Temperature

Output IP3 vs. Temperature

Output IP3 @ 0 dBm

Output IP3 @ 5 dBm

Output IP3 @ 10 dBm



**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3)	+5.5V
Gate Bias Voltage (Vgg1, 2)	-3 to 0V
Gain Control Voltage (Vctrl)	-3 to 0V
RF Power Input	+5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85 °C) (derate 10.2 mW/°C above 85 °C) [1]	0.92 W
Thermal Resistance (Channel to ground paddle)	97.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

12
VARIABLE GAIN AMPLIFIERS - ANALOG - SMT
Outline Drawing

BOTTOM VIEW

NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE
SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED
LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC694LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H694 XXXX
HMC694LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H694 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

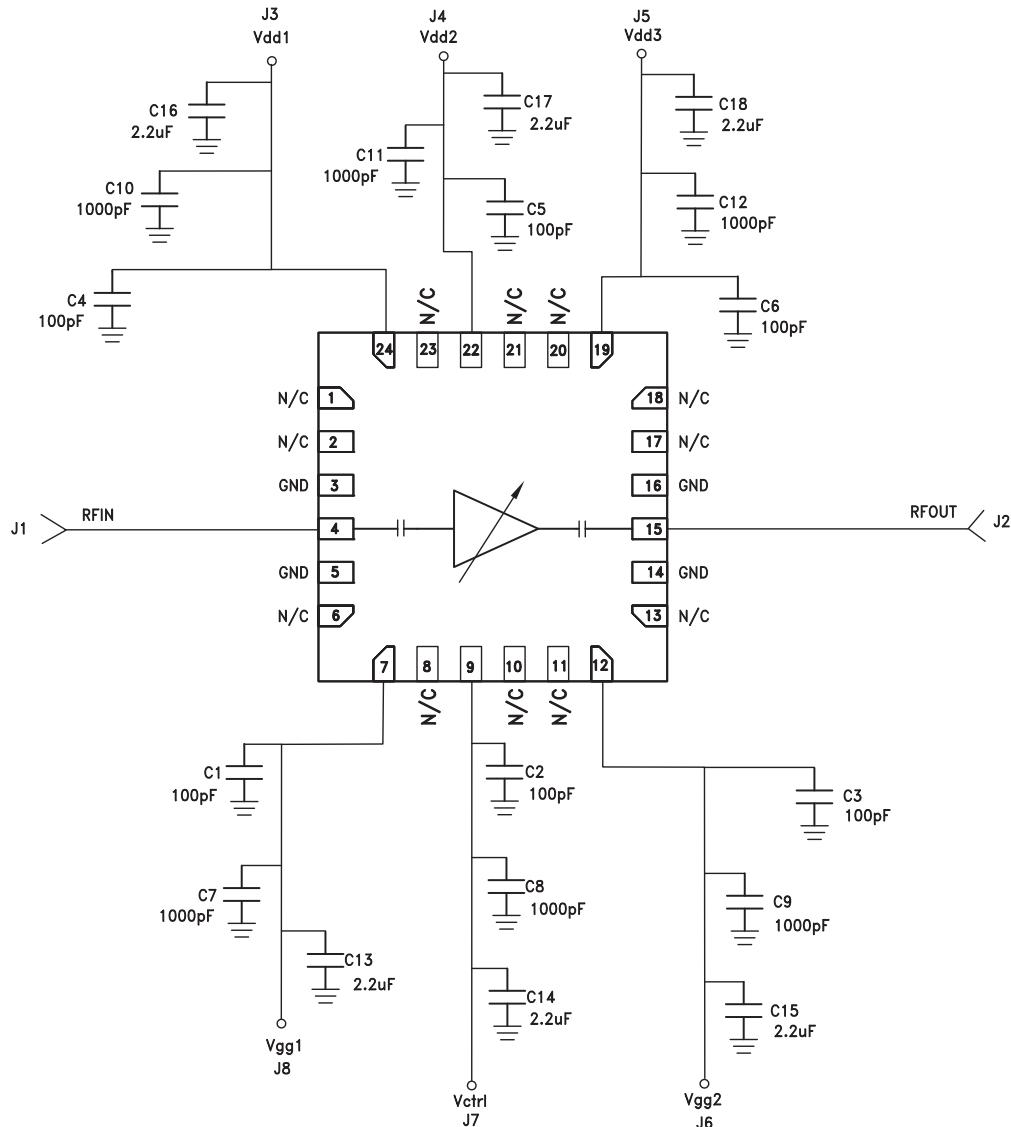
[3] 4-Digit lot number XXXX

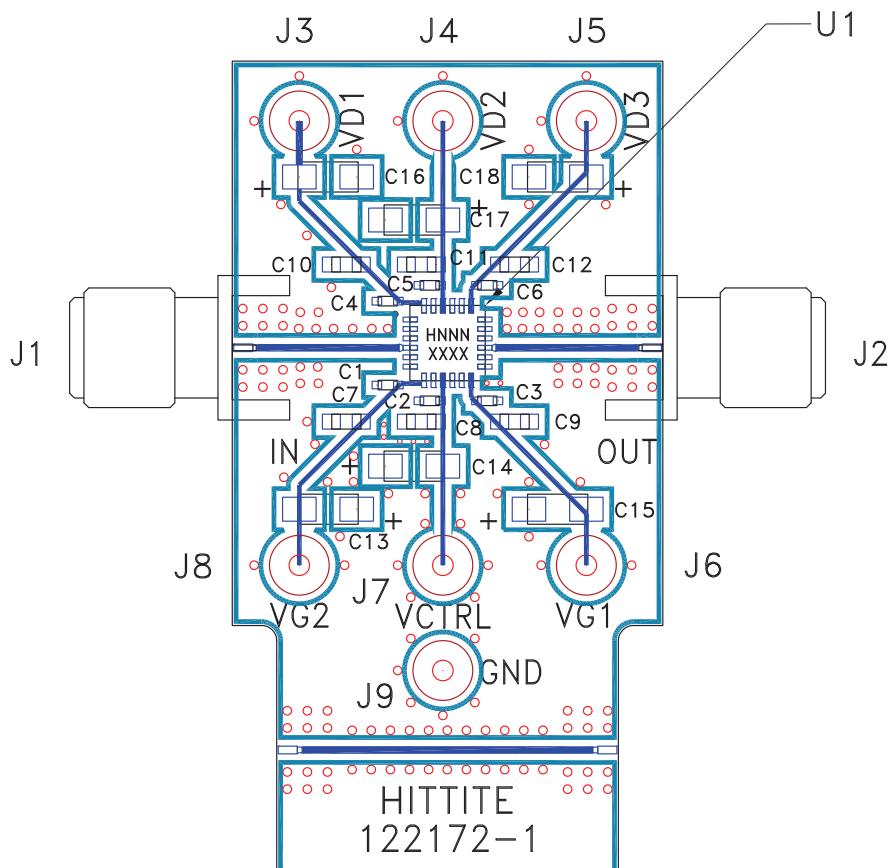
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**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Pin Descriptions

Pad Number	Function	Description	Interface Schematic
1, 2, 6, 8, 10, 11, 13, 17, 18, 20, 21, 23	N/C	No Connection	
3, 5, 14, 16	GND	Die bottom must be connected to RF/DC ground.	
4	RFIN	This pad is AC coupled and matched to 50 Ohm.	
7, 12	Vgg1, 2	Gate control for amplifier. Adjust voltage to achieve typical Idd. Please follow "MMIC Amplifier Biasing Procedure" application note.	
9	Vctrl	Gain control Voltage for the amplifier. See assembly diagram for required external components.	
15	RFOUT	This pad is AC coupled and matched to 50 Ohm.	
19, 22, 24	Vdd1, 2, 3	Drain Bias Voltage for the amplifier. See assembly diagram for required external components	


**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Application Circuit



**GaAs MMIC ANALOG VARIABLE
GAIN AMPLIFIER, 6 - 17 GHz**
Evaluation PCB

List of Materials for Evaluation PCB 122172^[1]

Item	Description
J1, J2	PCB Mount SMA RF Connectors
J3 - J9	DC Pin
C1 - C6	100 pF Capacitor, 0402 Pkg.
C7 - C12	1000 pF Capacitor, 0603 Pkg.
C13 - C18	2.2 μ F Capacitor, CASE A
U1	HMC694LP4(E) Variable Gain Amplifier
PCB ^[2]	122172 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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